



# Course guide

## 2301203 - PCR - Packaging, Characterization and Reliability

Last modified: 14/03/2024

**Unit in charge:** Barcelona School of Telecommunications Engineering  
**Teaching unit:** 1022 - UAB - (ANG) pendent.

**Degree:** MASTER'S DEGREE IN SEMICONDUCTOR ENGINEERING AND MICROELECTRONIC DESIGN (Syllabus 2024).  
(Optional subject).

**Academic year:** 2024    **ECTS Credits:** 6.0    **Languages:** English

### LECTURER

**Coordinating lecturer:** Consultar aquí / See here:

**Others:** Consultar aquí / See here:

### PRIOR SKILLS

Course "Semiconductor Facilities and Device Manufacturing",

### TEACHING METHODOLOGY

The methodology will combine master classes by the professors and hands-on exercises where the students will have to apply their knowledge to solve practical problems.

### LEARNING OBJECTIVES OF THE SUBJECT

- Describe the basic packaging techniques of devices and circuits and select the best option based on the specifications and applications.
- Identify in-line and wafer-level characterization and analysis techniques for fabrication processes and devices specific to nanotechnology and describe their fundamentals, being aware of their limitations.
- Identify and describe the fundamentals of failure/aging mechanisms and variability in nanodevices. Design accelerated reliability tests for lifetime estimation in nanoelectronics.
- Describe failure analysis techniques for technology assessment and gain hands-on experience.

### STUDY LOAD

Type	Hours	Percentage
Self study	102,0	68.00
Hours large group	30,0	20.00
Hours small group	18,0	12.00

**Total learning time:** 150 h

## CONTENTS

### Block 1. Packaging of devices and circuits

**Description:**

- 1.1 Introduction: Need for packaging. Single chip packages. Commonly used packages. Device Packaging types: THD (Through Hole Device), SMD (Surface Mounted Device), CSP (Chip Scale Packaging).
- 1.2 Materials and techniques. Wafer preparation and dicing. Die attaching. Wire bonding. Materials: metal, ceramics, polymers, glasses. Thermal behaviour and thermal mismatching.
- 1.3 Advanced packaging. Flip chip Bump Bonding. Current trends in packaging. Multichip modules (MCM). Hybrid circuits. System in package (SIP). Packaging roadmaps.
- 1.4 Issues. Parasitic resistance and capacity. Crosstalk. Power dissipation. Manufacturability. Testability. Reliability. Know Good Die problem. Lead-free alloys. Green electronics and RoHS compliance.

**Related activities:**

Master classes.

**Full-or-part-time:** 4h

Theory classes: 4h

### Block 2. Electrical characterization of processes and MOS devices

**Description:**

- 2.1 Characterization of the fabrication process. In-line measurements (profilometry, interferometry, ellipsometry, 4-point probe, ...). Test structures. Resistivity profiling by Differential Hall Effect and Spreading Resistance. Contact resistance measurements. Process qualification from C-V and current measurements (EOT, interfacial state density, Cox, flat band voltage...).
- 2.2 Electronic measurement systems for processes and devices characterization: wafer-probe stations, Source-Measurement Units, Semiconductor Parameter Analysers, C-V meters... Performance and limitations.
- 2.3 MOSFET performance evaluation: determination of performance parameters (threshold voltage, mobility, subthreshold swing...). Yield and process variability. Tests and test structures for compact model parameter extraction.
- 2.4 Reliability assessment
- 2.4.1 General concepts. Quality and reliability. Reliability modelling. Reliability of simple systems. Statistical distributions for reliability. Reliability of complex systems.
- 2.4.2 Reliability tests. Concept of reliability test. Accelerated tests. Introduction to Reliability Prediction Engineering.
- 2.4.3 Reliability in micro/nanoelectronics. Degradation/failure mechanisms in MOSFETs: Bias Temperature Instabilities, Hot Carrier Injection, Time-Dependent Dielectric Breakdown. Lifetime prediction. Other failure mechanisms: electromigration and ESD. Impact of CMOS scaling: time-dependent variability (TDV). Test structures, statistical characterization and modelling of the TDV. Reliability Simulation of integrated circuits: compact Models for TDV and Design for Reliability.

**Related activities:**

Master classes and hands-on work.

**Full-or-part-time:** 24h

Theory classes: 24h



### Block 3. Failure analysis

**Description:**

Fault location on the surface of an IC. Structural analysis and possible effects on its operation. Reconstruction of functionality and proposal of actions that mitigate/prevent/solve possible failures.

**Full-or-part-time:** 2h

Theory classes: 2h

## GRADING SYSTEM

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Final exam (40%) + Course work (60%)

## BIBLIOGRAPHY

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**Basic:**

- Ulrich, R.K.; Brown, W.D. Advanced electronic packaging. 2nd ed. Wiley-Interscience/IEEE, 2006. ISBN 9780471466093.
- Tummala, R.R.; Rymaszewski, E.J.; Klopfenstein, A.G. Microelectronics packaging handbook. 2nd ed. Kluwer Academic Publishers, 1997. ISBN 0412084317.
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- Selecting the right SMU. White paper, Keysight Technologies, 2023.
- Strong, A.W. [i 6 més]. Reliability wearout mechanisms in advanced CMOS technologies. Wiley-IEEE Press, 2009. ISBN 9780471731726.
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- Bazu, M.I.; Bajenescu, T.I. Failure analysis: a practical guide for manufacturers of electronic components and systems [on line]. Chichester, West Sussex, U.K: Wiley, 2011 [Consultation: 21/06/2024]. Available on: <https://onlinelibrary-wiley-com.recursos.biblioteca.upc.edu/doi/book/10.1002/9781119990093>. ISBN 9781119990093.